



UF4001 THRU UF4007

1.0 AMP SILICON RECTIFIERS



FEATURES

- * Low forward voltage drop
- * High current capability
- * High reliability
- * High surge current capability

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.34 grams

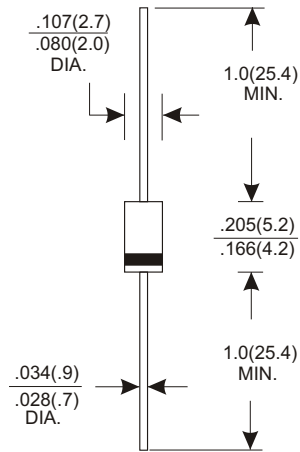
VOLTAGE RANGE

50 to 1000 Volts

CURRENT

1.0 Ampere

DO-41



Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	UF4001	UF4002	UF4003	UF4004	UF4005	UF4006	UF4007	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current 0.375"(9.5mm) Lead Length at $T_A = 55^\circ C$	$I_{(AV)}$	1							A
Peak Forward Surge Current, 8.3 ms Single Half-sine -wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	30							A
Maximum Forward Voltage at 1 A DC	V_F		1		1.3		1.7		V
Maximum Reverse Current at Rated DC Blocking Voltage $T_A = 25^\circ C$ $T_A = 100^\circ C$	I_R				5				μA
Typical Junction Capacitance ¹⁾	C_J				17				pF
Typical Thermal Resistance ²⁾	$R_{\theta JA}$				60				$^\circ C/W$
Maximum Reverse Recovery Time ³⁾	t_{rr}		50			75			ns
Operating and Storage Temperature Range	T_J, T_S	-55 to +150							$^\circ C$

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V DC.

²⁾ Thermal resistance junction to ambient and from junction to lead at 0.375"(9.5mm) lead length P.C.B mounted.

³⁾ Reverse recovery test conditions: $I_F = 0.5 A$, $I_R = 1 A$, $I_{rr} = 0.25 A$.

RATING AND CHARACTERISTIC CURVES (UF4001 THRU UF4007)

